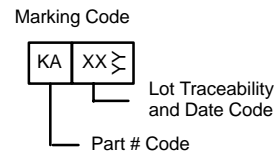
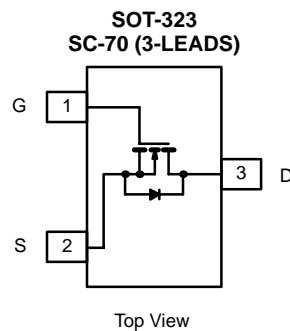




N-Channel 30-V (D-S) MOSFET

TrenchFET[®]
Power MOSFETs

PRODUCT SUMMARY		
V_{DS} (V)	$r_{DS(on)}$ (Ω)	I_D (A)
30	0.480 @ $V_{GS} = 10$ V	0.64
	0.700 @ $V_{GS} = 4.5$ V	0.53



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)					
Parameter		Symbol	5 secs	Steady State	Unit
Drain-Source Voltage		V_{DS}	30		V
Gate-Source Voltage		V_{GS}	± 20		
Continuous Drain Current ($T_J = 150^\circ\text{C}$) ^a	$T_A = 25^\circ\text{C}$	I_D	0.64	0.60	A
	$T_A = 70^\circ\text{C}$		0.51	0.48	
Pulsed Drain Current		I_{DM}	1.5		
Continuous Diode Current (Diode Conduction) ^a		I_S	0.26	0.23	
Maximum Power Dissipation ^a	$T_A = 25^\circ\text{C}$	P_D	0.31	0.28	W
	$T_A = 70^\circ\text{C}$		0.20	0.18	
Operating Junction and Storage Temperature Range		T_J, T_{stg}	-55 to 150		$^\circ\text{C}$

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^a	$t \leq 5$ sec	R_{thJA}	355	400	$^\circ\text{C/W}$
	Steady State		380	450	
Maximum Junction-to-Foot (Drain)	Steady State	R_{thJF}	285	340	

Notes

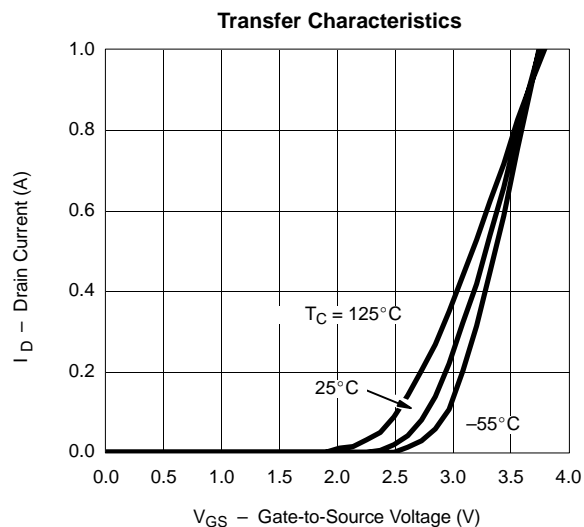
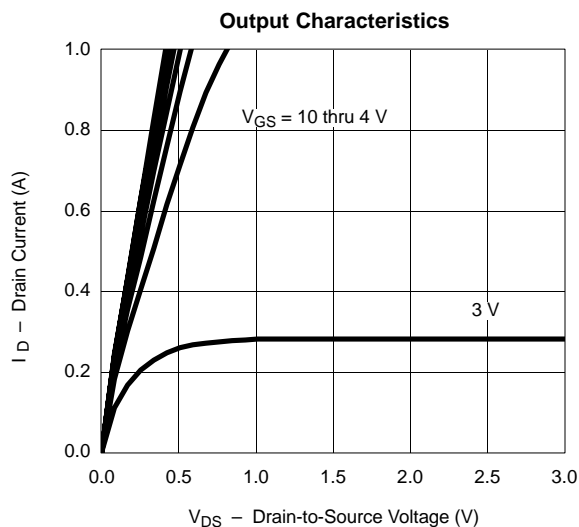
a. Surface Mounted on 1" x 1" FR4 Board.


SPECIFICATIONS (T_J = 25 °C UNLESS OTHERWISE NOTED)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Static						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 μA	1			V
Gate-Body Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ±20 V			±100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 24 V, V _{GS} = 0 V			1	μA
		V _{DS} = 24 V, V _{GS} = 0 V, T _J = 70 °C			5	
On-State Drain Current ^a	I _{D(on)}	V _{DS} = 5 V, V _{GS} = 10 V	1.5			A
Drain-Source On-State Resistance ^a	r _{DS(on)}	V _{GS} = 10 V, I _D = 0.6 A		0.410	0.480	Ω
		V _{GS} = 4.5 V, I _D = 0.2 A		0.600	0.700	
Forward Transconductance ^a	g _{fs}	V _{DS} = 15 V, I _D = 0.6 A		0.75		S
Diode Forward Voltage ^a	V _{SD}	I _S = 0.23 A, V _{GS} = 0 V		0.8	1.2	V
Dynamic^b						
Total Gate Charge	Q _g	V _{DS} = 15 V, V _{GS} = 10 V, I _D = 0.6 A		0.86	1.4	nC
Gate-Source Charge	Q _{gs}			0.24		
Gate-Drain Charge	Q _{gd}			0.08		
Turn-On Delay Time	t _{d(on)}	V _{DD} = 15 V, R _L = 30 Ω I _D ≅ 0.5 A, V _{GEN} = 10 V, R _G = 6 Ω		5	10	ns
Rise Time	t _r			8	15	
Turn-Off Delay Time	t _{d(off)}			8	15	
Fall Time	t _f			7	15	
Source-Drain Reverse Recovery Time	t _{rr}		I _F = 0.23 A, di/dt = 100 A/μs		15	

Notes

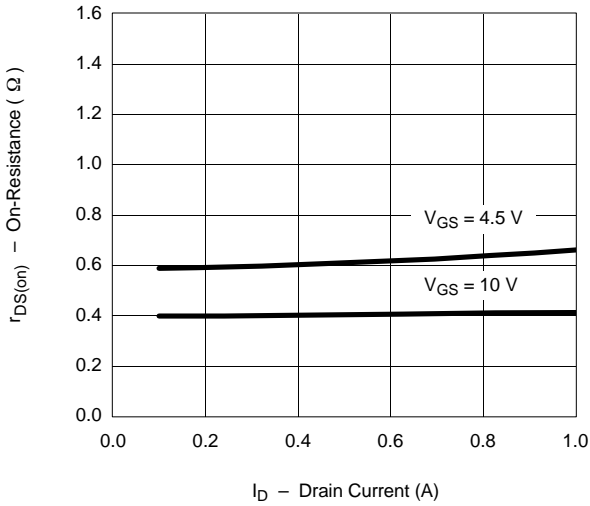
- a. Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2%.
b. Guaranteed by design, not subject to production testing.

TYPICAL CHARACTERISTICS (25 °C UNLESS NOTED)


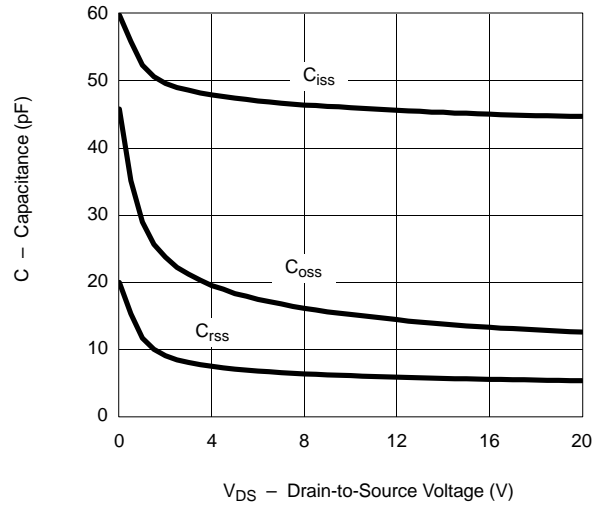


TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

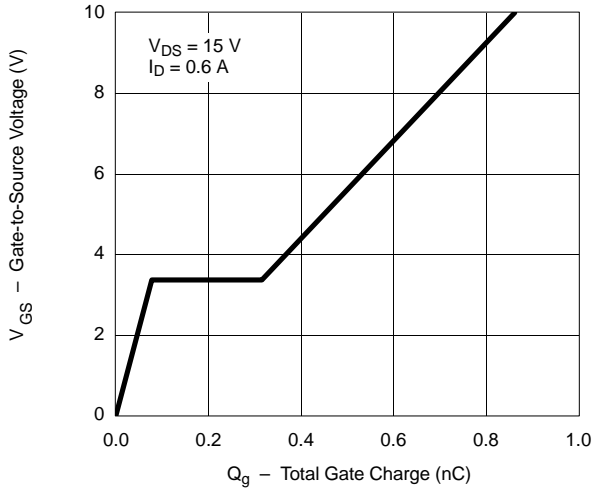
On-Resistance vs. Drain Current



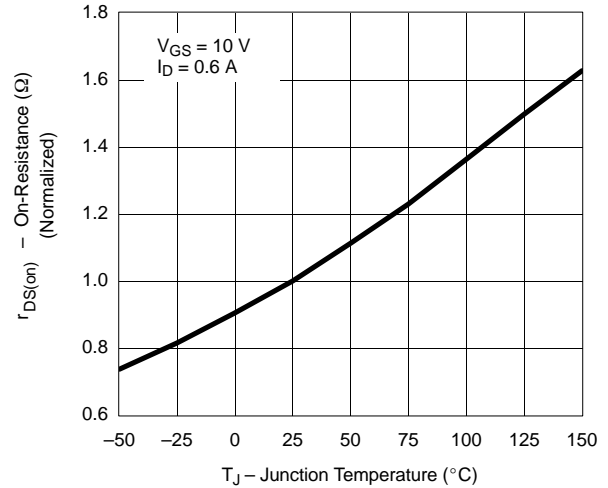
Capacitance



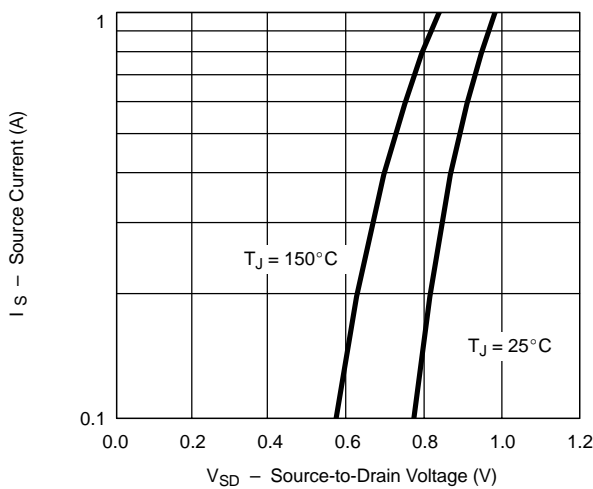
Gate Charge



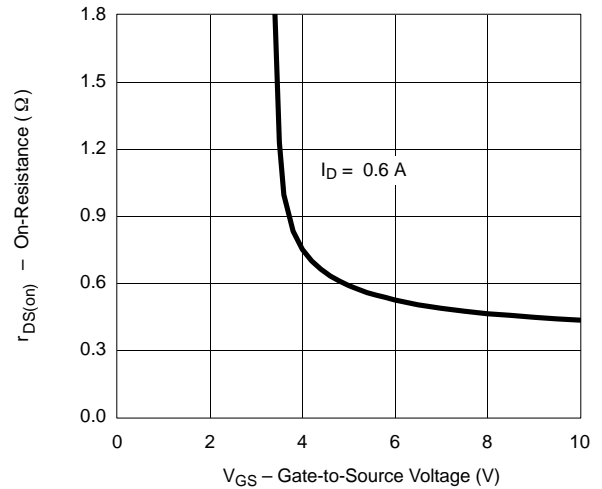
On-Resistance vs. Junction Temperature



Source-Drain Diode Forward Voltage

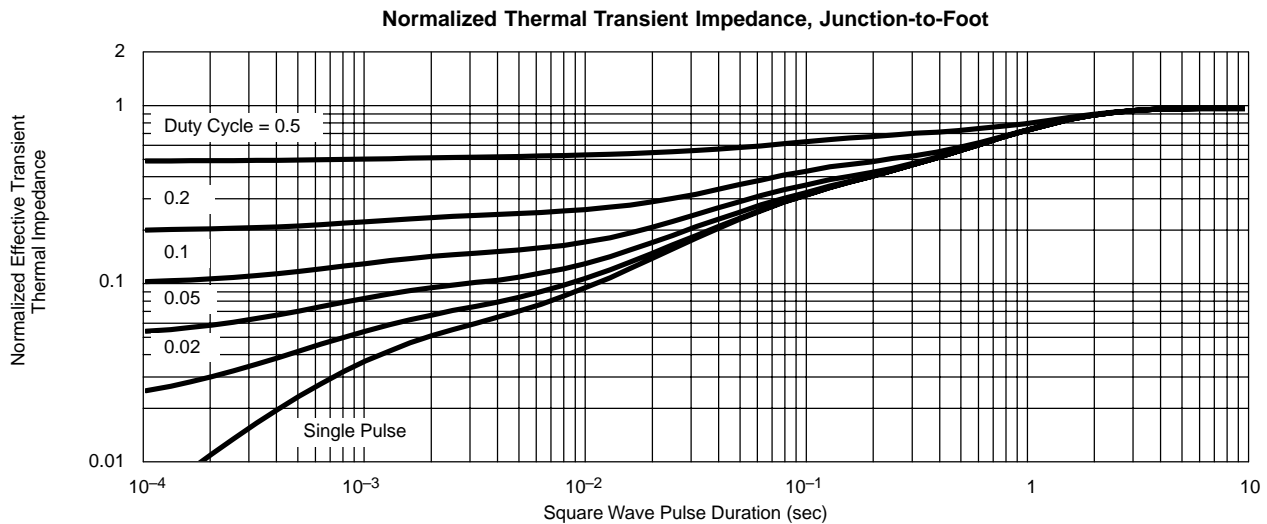
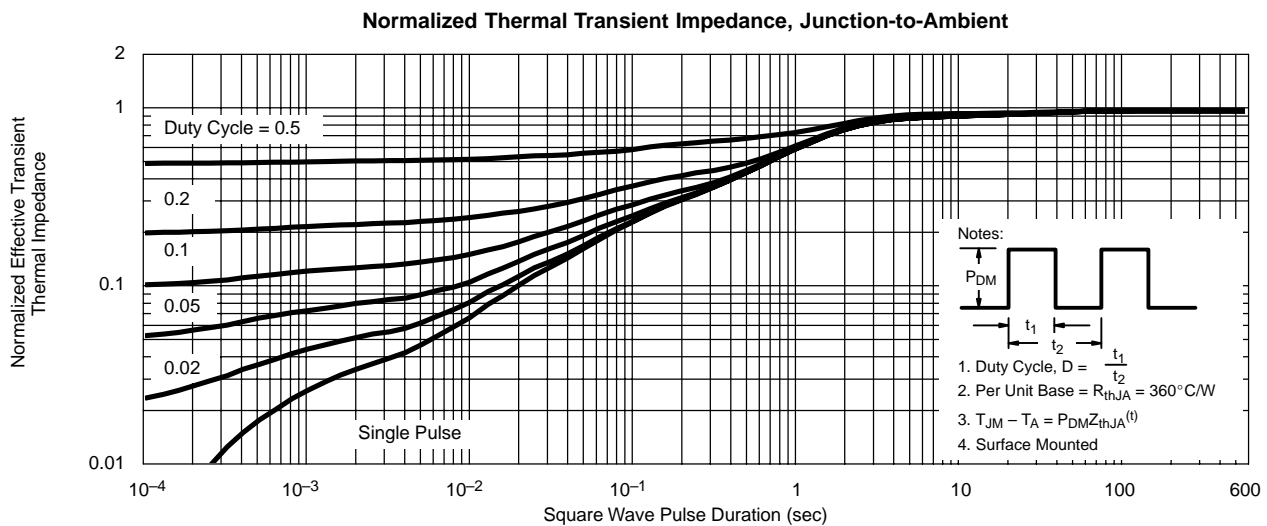
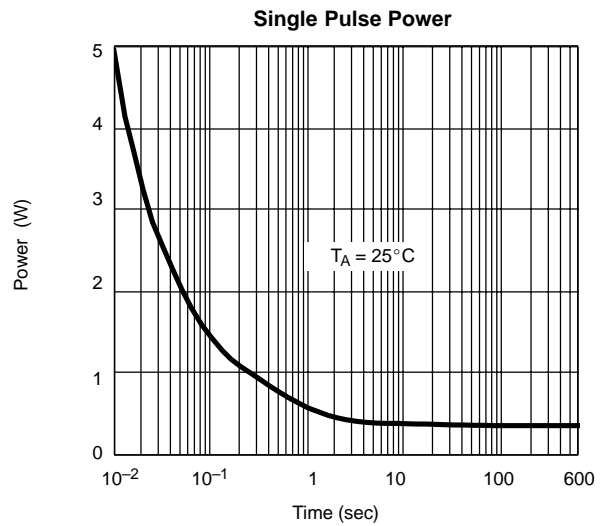
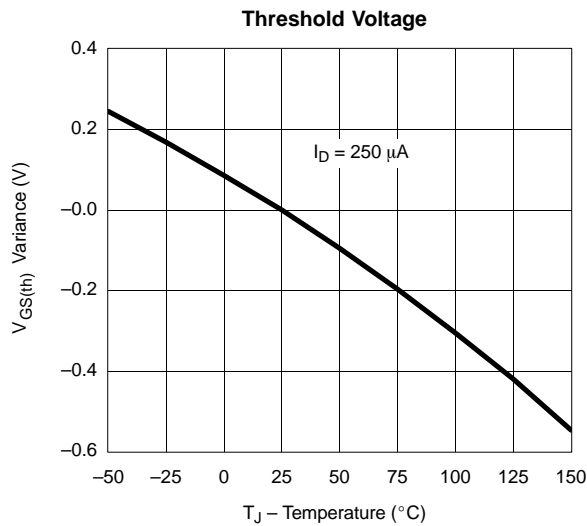


On-Resistance vs. Gate-to-Source Voltage





TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)





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